## NSN 5961-01-376-7516

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view Online at https://aerobasegroup.com/nsn/5961-01-376-7516
Inclosure Material:
Metal
Overall Length:
1.573 inches
Terminal Length:
Between 0.312 inches and 0.500 inches
Overall Height:
0.450 inches
Overall Width:
1.050 inches
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-3
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
650.0 collector to base voltage/static/emitter open and 650.0 collector to emitter voltage, dc with specified circuit between base and emitted to be a second or collector to emitter voltage.
and 400.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open
Current Rating Per Characteristic:
Between 5.00 amperes source cutoff current and 15.00 amperes source cutoff current
Power Rating Per Characteristic:
175.0 watts small-signal input power, common-collector preset
Transfer Ratio:
15.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Terminal surface option gold
Precious Material:
Gold
Test Data Document:
89954-348a1245 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

2 uninsulated wire lead and 1 case

**Terminal Type And Quantity:** 

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N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

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